

## National Taiwan Normal University CSU0007 - Basic Electronics Homework 5

100 points total. Due on 9AM, Monday, 6/8/2020.

Submit your answer via Moodle. Clearly state your analysis to earn full score. Please tweak your image files to help save some ink! For example, grey-out the background color. Thanks! 請影像處理您的作業照片以節省列印墨水(例如把背景顏色調淡)~謝謝!

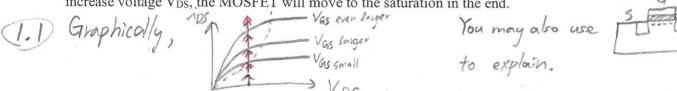
## We assume all MOSFETs have V<sub>T</sub>=1 V, K=1 mA/V<sup>2</sup>, and we use the SCS model.

Explain the following concepts in your own words. You may use figures to illustrate your points.

(10 points) Suppose that the MOSFET is in the cutoff region. If we fix voltage VDS (and suppose that V<sub>DS</sub> > 0) and gradually increase voltage V<sub>GS</sub>, the MOSFET will move to the other two regions in the following order:  $\rightarrow$  saturation  $\rightarrow$  triode.

(10 points) Suppose that the MOSFET is in the triode region. If we fix voltage  $V_{GS}$  and gradually 1.2

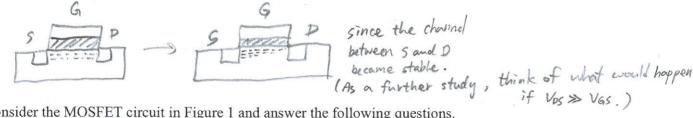
increase voltage V<sub>DS</sub>, the MOSFET will move to the saturation in the end.



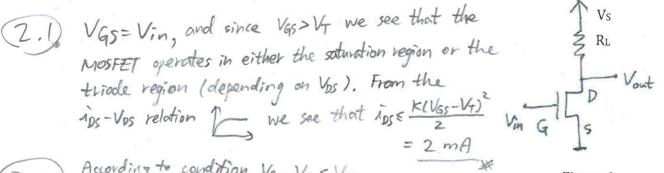
The condition to enter the triode region is Vas-VT = Vos, which implies

Git's fine to met ignore the = sign, because A in practice we would not operate A MOSPET at the boundary of regions. The "="

Vos of sign is for the purpose of illustration only.

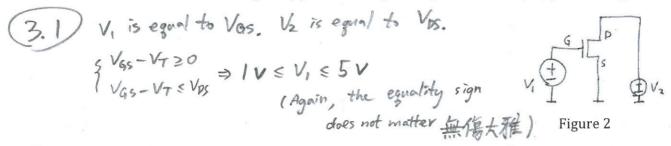


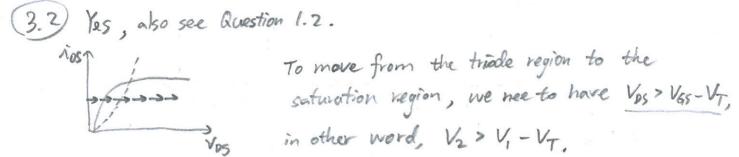
- Consider the MOSFET circuit in Figure 1 and answer the following questions.
  - (10 points) Suppose  $V_{in}=3$  V. Then  $i_{DS}=?$
  - (10 points) Suppose  $V_{in}=3$  V,  $V_{out}=5$  V, and  $R_L=10$  k $\Omega$ . Then  $V_S=?$



2.2) According to condition VGS-VT = VBS, Voit = 3 V implies that the MOSPET is operating in the scituration region. np = Vs - Vout and np = K(Vas-V7)2 gead to a conclusion that Vs = 7 V

- 3 Consider the MOSFET circuit in Figure 2.
  - 3.1 (5 points) Suppose  $V_2=4$  V. What would be the range of  $V_1$  for the MOSFET to operate in the saturation region?
  - 3.2 (5 points) Suppose that the MOSFET is operating in the triode region. Could we make the MOSFET to move into the saturation region by just increasing V<sub>2</sub>? If your answer is yes, give the range of V<sub>2</sub>.





4 (10 points) Consider the MOSFET amplifier in Figure 3. Assume the MOSFET is operating in the saturation region. Suppose  $V_S=15$  V,  $R_L=5$  k $\Omega$ , and  $V_{in}=3$ V. Compute the gain for this configuration.

the gain = 
$$\frac{Vout}{Vin}$$
 in this case.

From  $\begin{cases} ios = \frac{K(Vin - V_7)^2}{2} \\ ios = \frac{Vs - Vout}{RL} \end{cases}$ 

we have  $\frac{1 \times 10^3 (3-1)^2}{2} = \frac{15 - Vout}{5 \times 10^3}$ 
 $\Rightarrow Vout = 15 - 10 = 5 V$ 
 $\Rightarrow \frac{Vout}{Vin} = \frac{5}{3} \times \frac{10^3}{Vin}$ 

Figure 3

$$(9 - V_{in}) \le 15 - (9 - V_{in})^{2} = 15 - (9 - V_{in})^{2}$$

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$$(9 - V_$$

- Consider the MOSFET amplifier in Figure 4. Suppose that the MOSFET is in the saturation region, and  $V_S=15~V,~R_1=5~k\Omega,~R_2=10~k\Omega$ , and  $R_3=2~k\Omega$ . (Note: If you've downloaded the earlier version of the lecture note, make sure you've made the following correction: the last equation on page 77 should have a square over the parenthesis.)
  - 5.1 (5 points) If V<sub>in</sub>=8 V. Find V<sub>out</sub>.
  - 5.2 (5 points) Find the minimum value of V<sub>in</sub> for the MOSFET to stay in the saturation region.
  - 5.3 (5 points) If we can change R<sub>3</sub>, what is the maximum value of R<sub>3</sub> for the MOSFET to stay in the saturation region?
  - 5.4 (5 points) What is the maximum V<sub>in</sub> that will make the gain larger than or equal to 1?

5.) 
$$V_{GS} = (\text{the branch voltage across } R_2) - V_{in}$$

$$= (15 \times \frac{10}{5+10}) - V_{in} = 10 - V_{in}$$

$$V_{out} = V_S - 10S \cdot R_3 \quad (\text{from } 10S = \frac{V_S - V_{out}}{R_3})$$

$$= V_S - \frac{K(V_{GS} - V_T)^2}{2} \cdot R_3 \Rightarrow V_{out} = 15 - (9 - V_{in})^2$$

$$V_{in} = 8 \text{ V} \Rightarrow V_{out} = 14$$

$$\begin{cases} V_{GS} - V_{T} \ge 0 \\ V_{GS} - V_{T} \le V_{DS} \end{cases} = \begin{cases} 10 - V_{in} - 1 \ge 0 \\ 10 - V_{in} - 1 \le V_{out} = 15 - (9 - V_{in})^{2} \end{cases} \Rightarrow \begin{cases} V_{in} \le 9 \\ 5.59 \le V_{in} \le 13.4 \end{cases}$$

$$\Rightarrow \text{ minimum } V_{in} \approx 5.59$$

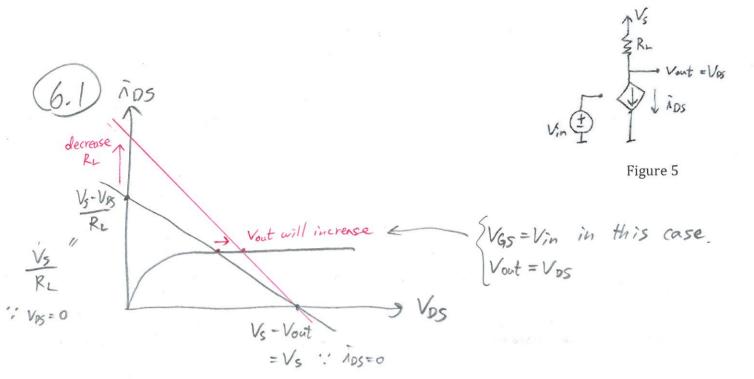
(5.3) following (5.1), from Vout = 
$$V_s - \frac{K(V_{GS}-V_{\overline{O}})^2}{2}R_3$$
  

$$\Rightarrow V_{DS} = V_{out} - V_{in} = 15 - \frac{|x|o^{-3}(9-V_{in})^2}{2}R_3 - V_{in}$$

the condition is 
$$V_{ps} \ge V_{qs} - V_{T}$$
  
 $\Rightarrow 15 - \frac{1}{2} \times 10^{3} (9 - V_{in})^{2} \cdot R_{3} - V_{in} \ge (10 - V_{in}) - 1$   
if  $V_{in} = 8 \ V \Rightarrow 15 - \frac{1}{2} \times 10^{-3} \cdot R_{3} \ge 9 \Rightarrow R_{3} \le 12 \ k \ \Sigma$ 

(5.4) 
$$V_{out} = f(V_{in}) = 15 - (9 - V_{in})^2$$
  
 $f'(V_{in}) = 2(9 - V_{in})$  goin = 切錄計算  
 $f'(V_{in}) \ge 1 \Rightarrow 2(9 - V_{in}) \ge 1$   
 $\Rightarrow V_{in} \le 8.5 \text{ V}$ 

- 6 Consider the MOSFET amplifier in Figure 5.
  - 6.1 (5 points) Apply the graphical analysis to explain the following phenomenon: if we decrease  $R_L$ , then the same  $V_{in}$  will produce a larger  $V_{out}$ .
  - 6.2 (5 points) Apply the graphical analysis to illustrate an example that if we increase V<sub>T</sub>, the valid range of V<sub>in</sub> for the MOSFET to stay in the saturation region will decrease.

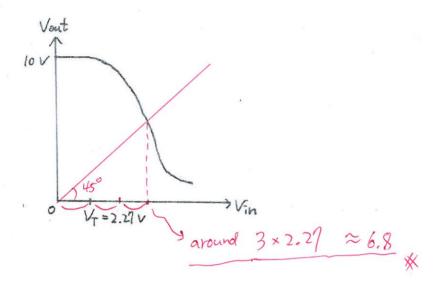


6.2) We've discussed this in class, saying that this analysis and observation make sense only if the Vin-Vout relation does not change as we change VT.

the new valid range the old valid range.

this necessary condition is not true, since changing V7 usually means we've changed the physical properties of the MOSFET.

Apply the graphical analysis for the following two questions. Consider the MOSFET amplifier in Figure 5.
 7.1 (5 points) Suppose the following plot of Vout-Vin relation is accurate. To estimate the maximum Vin for the MOSFET to stay in the saturation region, which one of the following three estimation is better than the other two, and why? (A) 4.2 V; (B) 6.8; (C) 8.1.



7.2 (5 points) Following Question 7.1, suppose  $V_{GSmax}$  in the following plot is our estimation of the maximum  $V_{in}$ . Determine the value of  $V_Z$ .

